

GGFT3356 - 7GHz NPN Silicon Epitaxial High-Frequency Transistor

| Part No. | Main Parameter | | | | | | Package |
|----------|----------------|----------|----------|---------|--------|----------------------|-----------|
| | VCBO (V) | VCEO (V) | VEBO (V) | Ic (mA) | HFE | f _T (GHz) | |
| GGFT3356 | 20 | 12 | 3 | 100 | 50-300 | 7 | SOT-23-3L |

* Features

- + Low Noise and High Gain: NF=1.1dB TYP, Ga=11dB TYP.@VCE=10V, IC=7mA, f=1.0GHz
- + High Power Gain: MAG=13dB TYP.@VCE=10V, IC=20mA, f=1.0GHz
- + HFE Spec: 50-300;

* Applications

- + Low Noise amplifier for VHF,UHF & CATV band

